

SEMICONDUCTOR IM

General Description:

Schottky Barrier Diodes make use of the rectification effect of a metal to silicon barrier. They are ideally suited for high frequency rectification in switching regulators & converters. This device offers a low forward voltage performance in a power surface mount package in applications where size and weight are critical.

Features:

MBR0520L

SCHOTTKY POWER RECTIFIER

- Compact surface mount with same footprint as mini-melf
- 400 milliwatt Power Dissipation package.
- 1.0 Ampere, forward voltage less than 600 mv

Ordering:

• 7 inch reel (178 mm); 8 mm Tape; 3,000 units per reel.

Absolute Maximum Ratings (note 1) TA = 25°C unless otherwise noted

| Parameter | Value | Units |
|---|-------------|-------|
| Storage Temperature | -65 to +150 | °C |
| Maximum Junction Temperature | -65 to +125 | OO |
| Repetitive Peak Reverse Voltage (V _{RRM}) | 20 | V |
| Working Peak Reverse Voltage (V _{RWM}) | 20 | V |
| DC Blocking Voltage (V _R) | 20 | V |
| Average Rectified Forward Current (Rated V _R) | 500 | mA |
| Surge Non Repetitive Forward Current | 5.5 | A |
| (Surge applied at rated load conditions | | |
| half wave, single phase, 60 Hz) | | |
| Thermal Resistance ($R_{ØJA}$) Junction to Ambient (note 2) | 340 | °C/W |
| Thermal Resistance (R _{ØJL}) Junction to Lead | 150 | °C/W |

Note 1: These ratings are limiting values above which the serviceability of any semiconductor device may be impaired

TA = 25°C unless otherwise noted

Note 2: FR-4 or FR-5 = 3.5×1.5 inches using minimum recommended Land Pads.

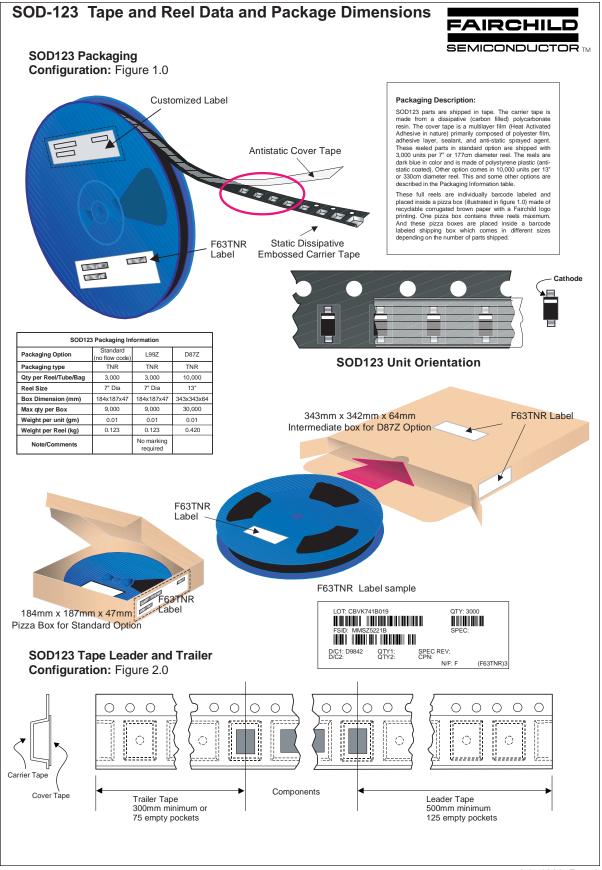


Actual Size

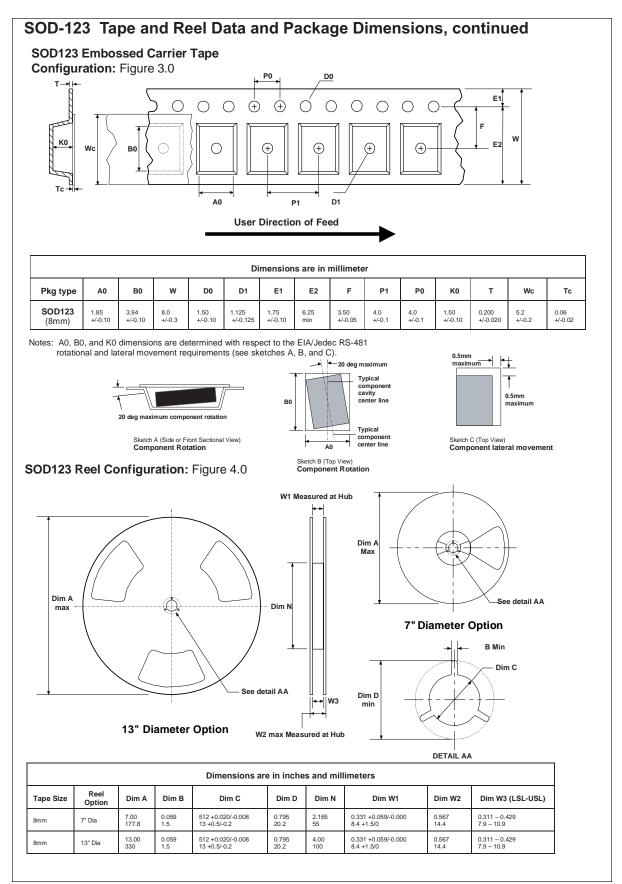
| SYM | CHARACTERISTICS | MIN | МАХ | UNITS | TEST CONDITIONS |
|-------------------|--|-----|--------------------------|----------------------|---|
| I _R Re | verse Leakage | | 75 5.0 250 8.0 | uA mA uA mA | $ \begin{array}{rcl} V_{\rm R} = & 10 \ V & T_{\rm A} = 25^{\rm O}{\rm C} \\ V_{\rm R} = & 10 \ V & T_{\rm A} = 100^{\rm O}{\rm C} \\ V_{\rm R} = & 20 \ V & T_{\rm A} = 25^{\rm O}{\rm C} \\ V_{\rm R} = & 20 \ V & T_{\rm A} = 100^{\rm O}{\rm C} \end{array} $ |
| | rward Voltage V _F Pulse width = 300 us, Duty Cycle <u><</u> 2% | | 300 220 385 330 | mV mV mV mV | $ I_{F} = 100 \text{ mA } T_{A} = 25^{\circ}\text{C} $ $ I_{F} = 100 \text{ mA } T_{A} = 100^{\circ}\text{C} $ $ I_{F} = 500 \text{ mA } T_{A} = 25^{\circ}\text{C} $ $ I_{F} = 500 \text{ mA } T_{A} = 100^{\circ}\text{C} $ |

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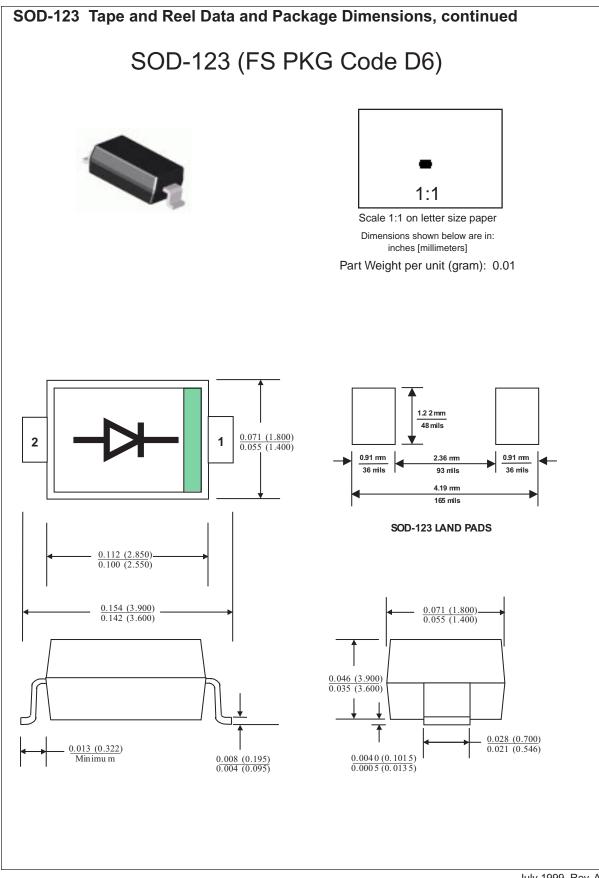
Electrical Characteristics



July 1999, Rev. A



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PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|---------------------------|---|
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